

Device Modeling Report

COMPONENTS:

DIODE/ SCHOOTTKY RECTIFIER /STANDARD

PART NUMBER: U1FWJ44M

MANUFACTURER: TOSHIBA

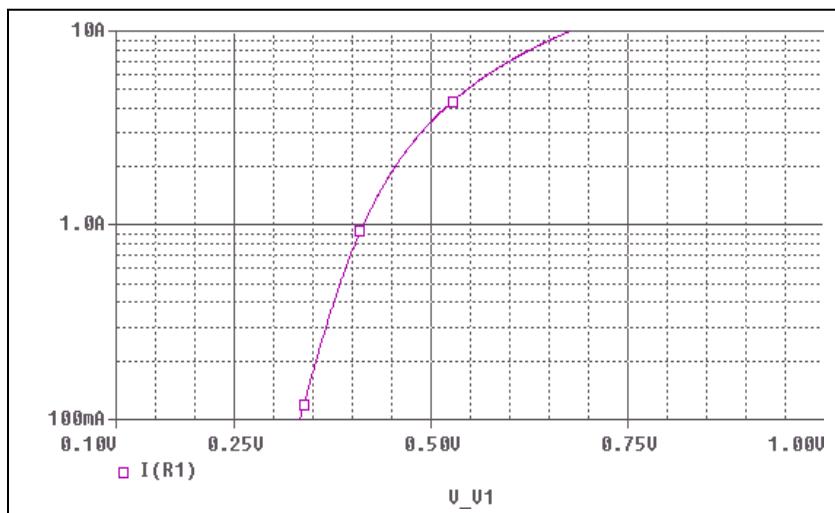


Bee Technologies Inc.

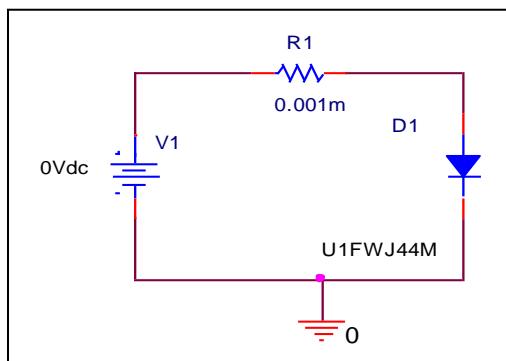
PSpice model parameter	Model description
IS	Saturation Current
N	Emission Coefficient
RS	Series Resistance
IKF	High-injection Knee Current
CJO	Zero-bias Junction Capacitance
M	Junction Grading Coefficient
VJ	Junction Potential
ISR	Recombination Current Saturation Value
BV	Reverse Breakdown Voltage(a positive value)
IBV	Reverse Breakdown Current(a positive value)
TT	Transit Time
EG	Energy-band Gap

Forward Current Characteristic

Circuit Simulation Result

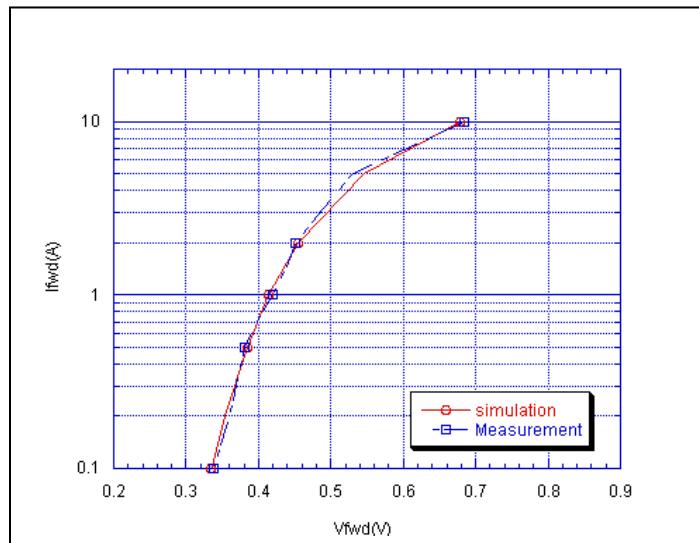


Evaluation Circuit



Comparison Graph

Circuit Simulation Result

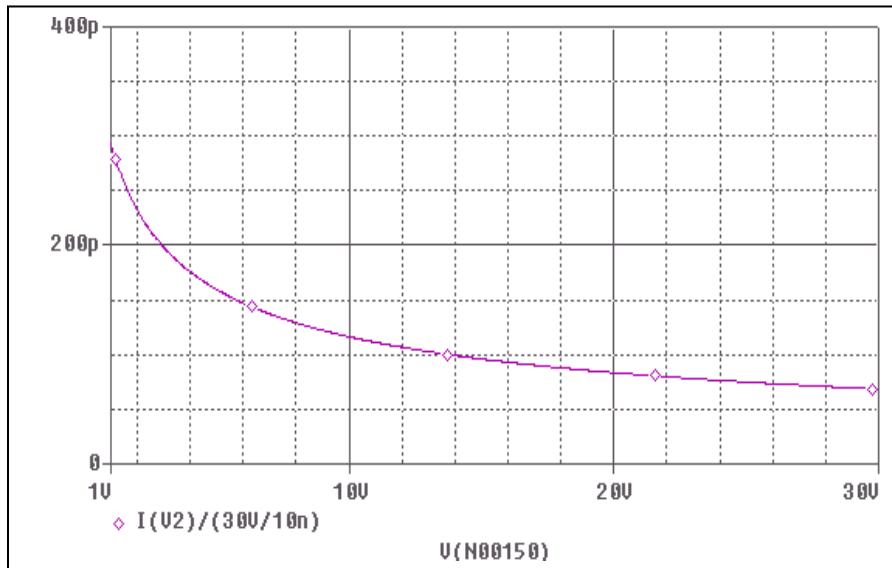


Simulation Result

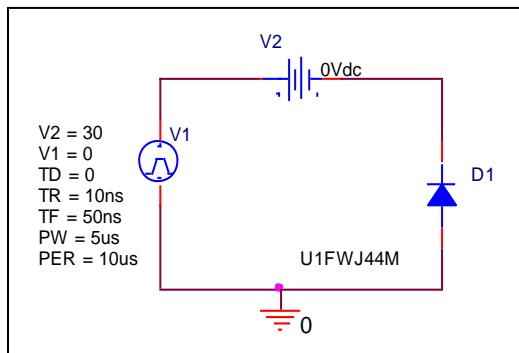
$I_{fwd}(A)$	$V_{fwd}(V)$ Measurement	$V_{fwd}(V)$ Simulation	%Error
0.1	0.338	0.334	-1.24
0.2	0.360	0.354	-1.69
0.5	0.380	0.384	1.11
1	0.420	0.414	-1.52
2	0.450	0.454	0.96
5	0.530	0.546	2.94
10	0.685	0.678	-1.07

Junction Capacitance Characteristic

Circuit Simulation Result

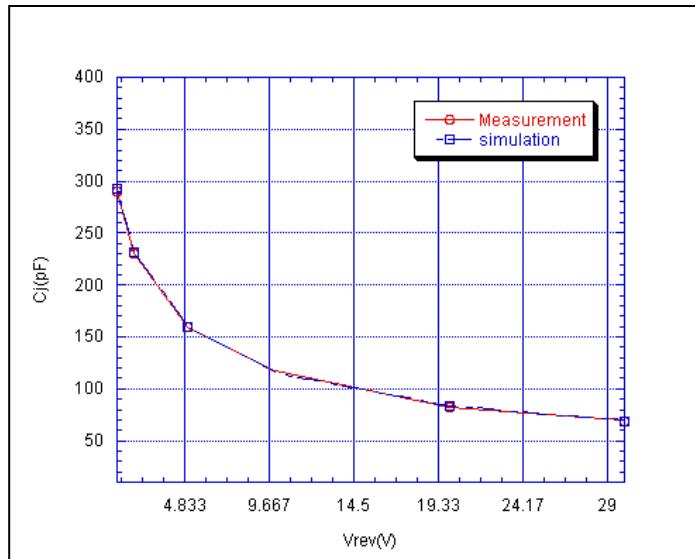


Evaluation Circuit



Comparison Graph

Circuit Simulation Result



Simulation Result

Vrev(V)	Cj(pF) Measurement	Cj(pF) Simulation	%Error
1	290.00	292.94	1.01
2	230.00	231.73	0.75
5	160.00	159.61	-0.24
10	117.00	116.31	-0.59
20	82.00	83.50	1.83
30	69.00	68.65	-0.51